

Section 16

Recombination & Generation

16.4 Direct and Auger Recombination

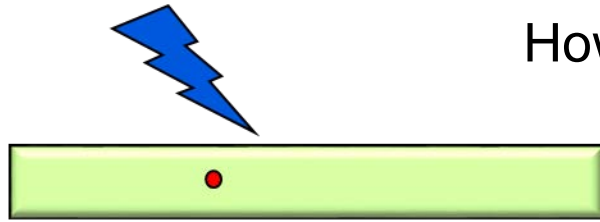
Gerhard Klimeck
gekco@purdue.edu



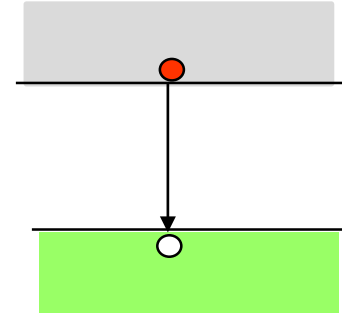
School of Electrical and
Computer Engineering

Section 16

Recombination & Generation



How does the system go BACK to equilibrium?



$$\tau_n = \frac{1}{c_n N_T} \quad \tau_p = \frac{1}{c_p N_T}$$

$$n_1 = n_i g_D e^{\beta(E_T - E_i)}$$

$$p_1 = n_i g_D^{-1} e^{\beta(E_i - E_T)}$$

$$R = \frac{pn - n_i^2}{\tau_p(n + n_1) + \tau_n(p + p_1)}$$

$$R = \frac{\Delta n}{\tau_n}$$

$$R = \frac{\Delta n}{(\tau_n + \tau_p)}$$

- 16.1 Capture coefficient & Capture Cross Section
- 16.2 Derivation of SRH formula (Shockley, Reed, Hall)
 - » 16.2.1 Trap Assisted Recombination Rates
 - » 16.2.2 Capture and emission relationship (n_1 and p_1)
 - » 16.2.3 Steady State Trap Population
 - » 16.2.4 Recombination-Generation Rate
- 16.3 Application of SRH formula for special cases
 - » Low level, high-level injection, depletion region
- 16.4 Direct and Auger recombination
- 16.5
- 16.6
- 16.7



Vid

>

>

>

>

Video

>

>

>

>

Band-to-band Recombination

$$R = B \left(np - n_i^2 \right) \quad B \text{ is a material property}$$

Direct recombination at low-level injection

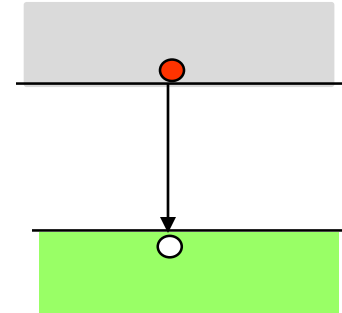
$$n_0 \ll (\Delta n = \Delta p) \ll p_0$$

$$R = B \left[(n_0 + \Delta n)(p_0 + \Delta p) - n_i^2 \right] \approx B p_0 \times \Delta n$$

Direct generation in depletion region

$$n, p \sim 0$$

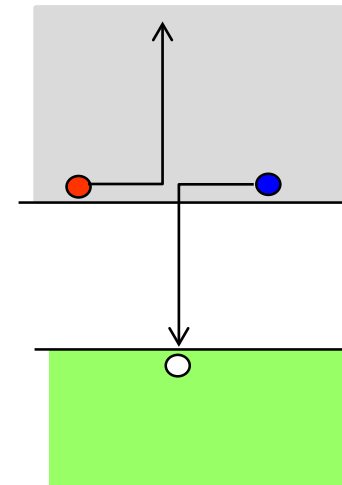
$$R = B \left(np - n_i^2 \right) \approx -B n_i^2$$



Auger Recombination

2 electron & 1 hole

$$R = c_n (n^2 p - n_i^2 n) + c_p (np^2 - n_i^2 p)$$
$$c_n, c_p \sim 10^{-29} \text{ cm}^6/\text{sec}$$



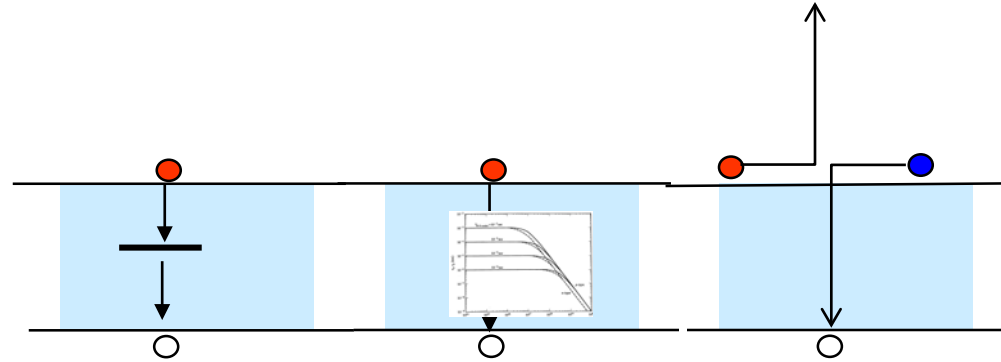
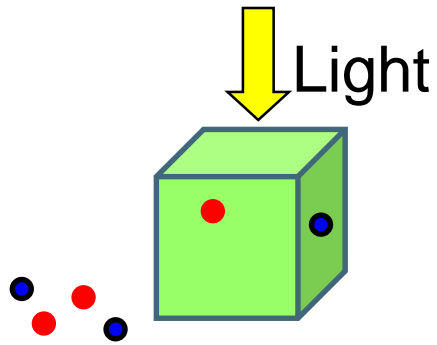
Auger recombination at low-level injection

$$n_0 \ll (\Delta n = \Delta p) \ll (p_0 = N_A)$$

$$R \approx c_p N_A^2 \Delta n = \frac{\Delta n}{\tau_{auger}} \quad \tau_{auger} = \frac{1}{c_p N_A^2}$$

Dominant recombination in heavy doped semiconductors

Effective Carrier Lifetime

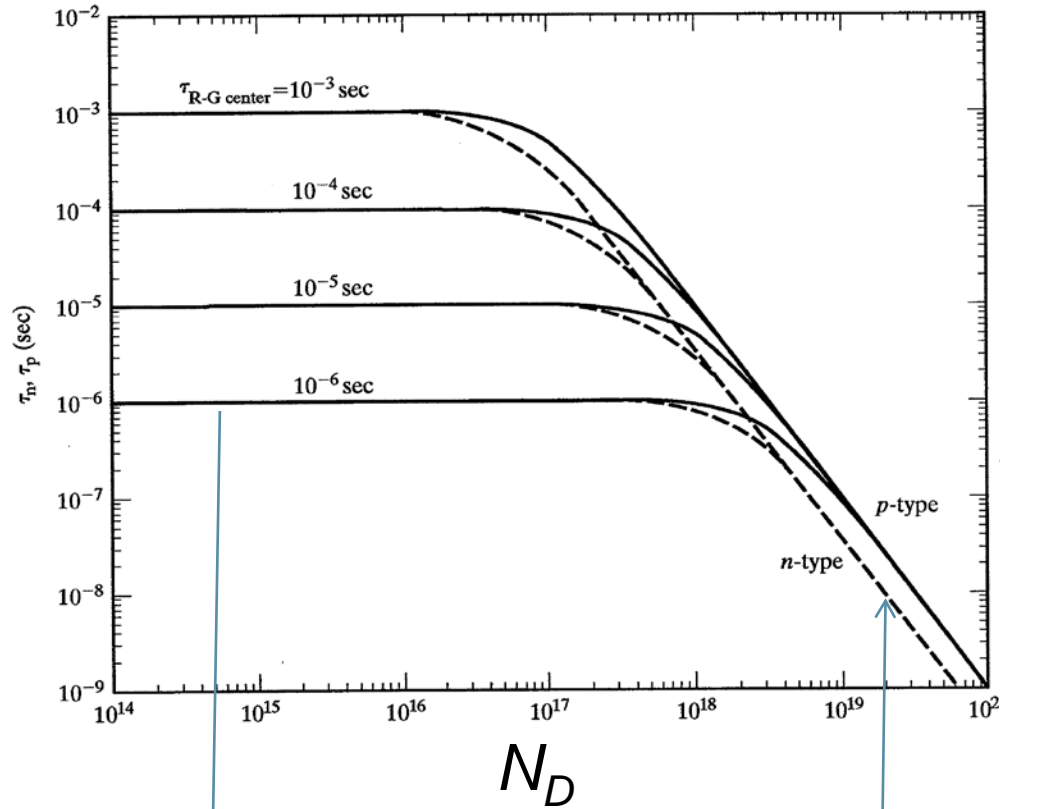


$$\Delta n(t) = \Delta n(t=0) e^{-\frac{t}{\tau_{eff}}}$$

$$\tau_{eff} = \left(c_n N_T + B N_D + c_{n, auger} N_D^2 \right)^{-1}$$

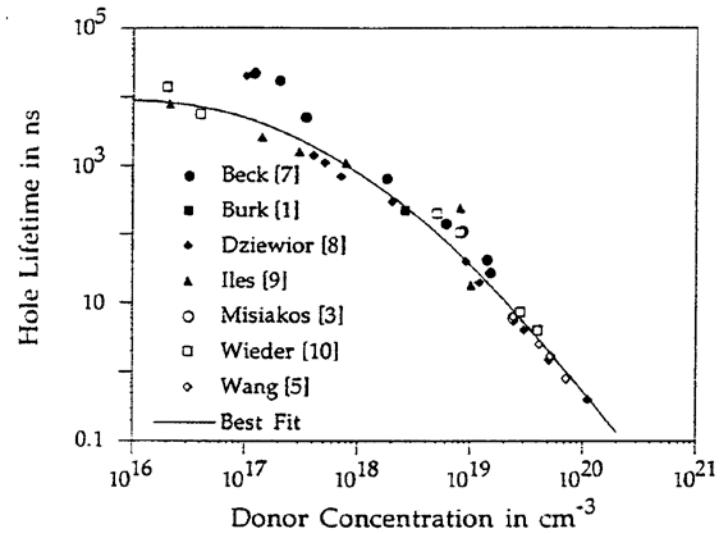
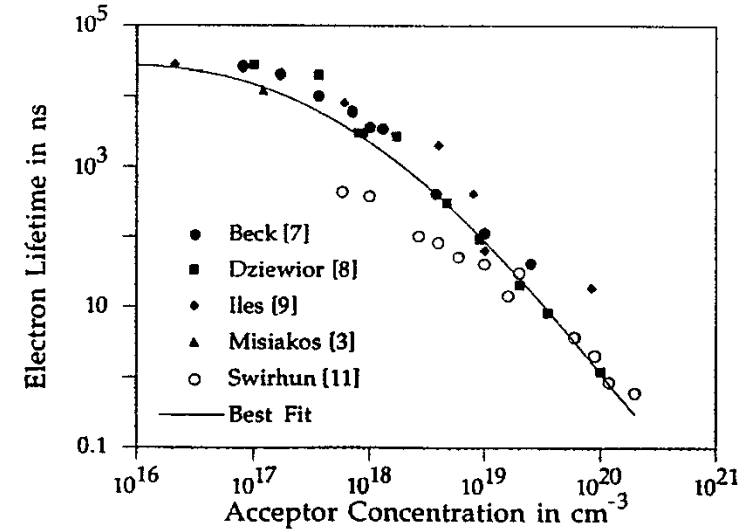
$$\begin{aligned} R &= R_{SRH} + R_{direct} + R_{Auger} \\ &= \Delta n \left(\frac{1}{\tau_{SRH}} + \frac{1}{\tau_{direct}} + \frac{1}{\tau_{Auger}} \right) \\ &= \Delta n \left(c_n N_T + B N_D + c_{n, auger} N_D^2 \right) \end{aligned}$$

Effective Carrier Lifetime with all Processes

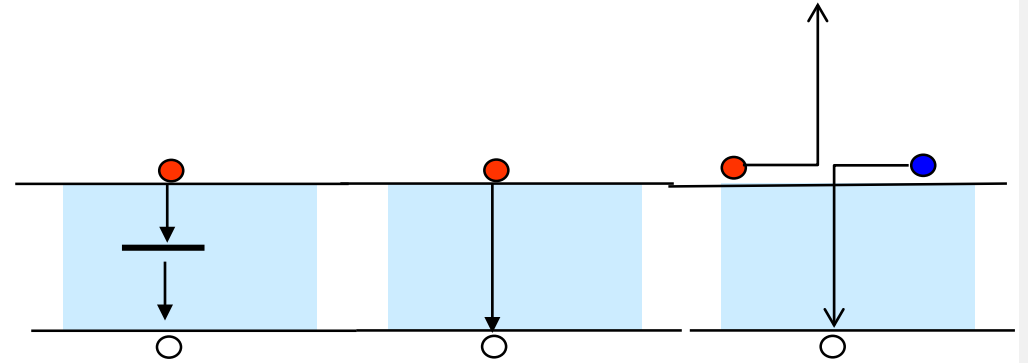
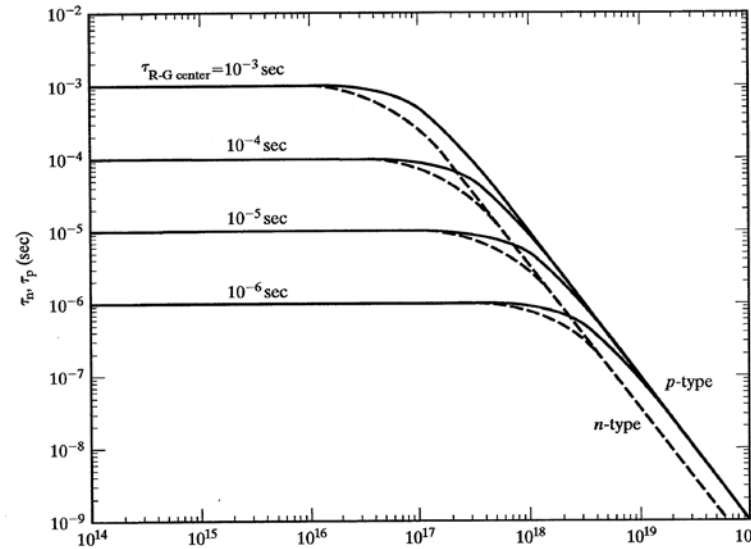


$$\tau_{eff} \approx c_{n, auger} N_D^{-2}$$

$$\tau_{eff} = \left(c_n N_T + B N_D + c_{n, auger} N_D^2 \right)^{-1}$$



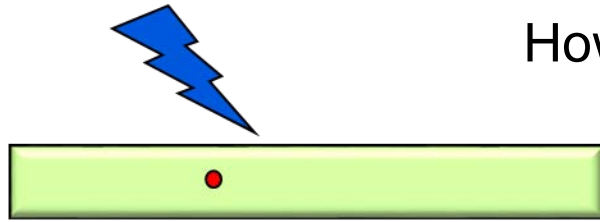
Conclusion



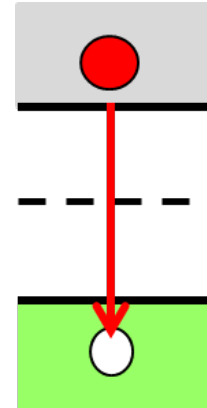
- SRH is an important mechanism in important semiconductors like Si and Ge.
- SRH formula is complicated
=> simplification for special cases are often desired.
- Direct band-to-band and Auger recombination
=> can also be described with simple phenomenological formula.
- Expressions widely validated by measurements.

Section 16

Recombination & Generation



How does the system go BACK to equilibrium?



$$\tau_n = \frac{1}{c_n N_T} \quad \tau_p = \frac{1}{c_p N_T}$$

$$n_1 = n_i g_D e^{\beta(E_T - E_i)}$$

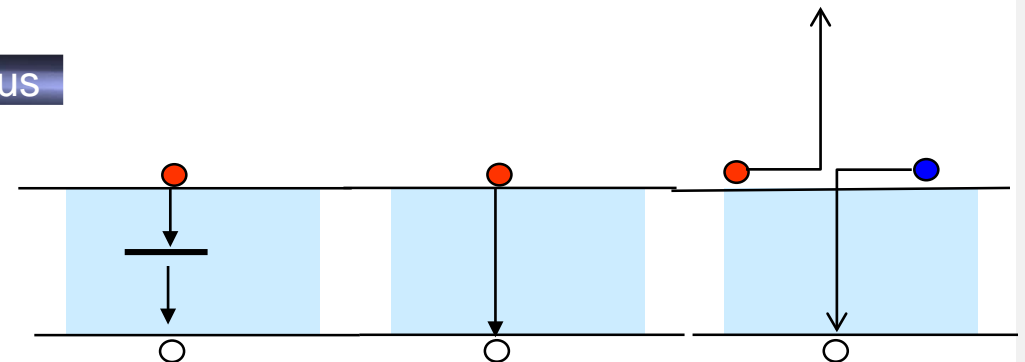
$$p_1 = n_i g_D^{-1} e^{\beta(E_i - E_T)}$$

$$R = \frac{pn - n_i^2}{\tau_p(n + n_1) + \tau_n(p + p_1)}$$

$$R = \frac{\Delta n}{\tau_n}$$

$$R = \frac{\Delta n}{(\tau_n + \tau_p)}$$

- 16.1 Capture coefficient & Capture Cross Section
- 16.2 Derivation of SRH formula (Shockley, Reed, Hall)
 - » 16.2.1 Trap Assisted Recombination Rates
 - » 16.2.2 Capture and emission relationship (n_1 and p_1)
 - » 16.2.3 Steady State Trap Population
 - » 16.2.4 Recombination-Generation Rate
- 16.3 Application of SRH formula for special cases
 - » Low level, high-level injection, depletion region
- 16.4 Direct and Auger recombination
- 16.5 Nature of interface states
- 16.6
- 16.7



Vid

>

>

>

>

Video

>

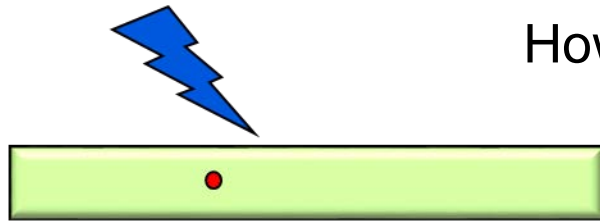
>

>

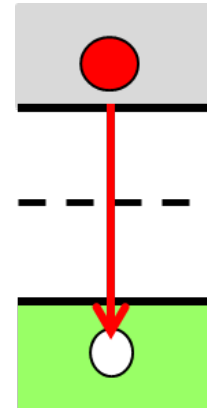
>

Section 16

Recombination & Generation



How does the system go BACK to equilibrium?



$$\tau_n = \frac{1}{c_n N_T} \quad \tau_p = \frac{1}{c_p N_T}$$

$$n_1 = n_i g_D e^{\beta(E_T - E_i)}$$

$$p_1 = n_i g_D^{-1} e^{\beta(E_i - E_T)}$$

$$R = \frac{pn - n_i^2}{\tau_p(n + n_1) + \tau_n(p + p_1)}$$

$$R = \frac{\Delta n}{\tau_n}$$

$$R = \frac{\Delta n}{(\tau_n + \tau_p)}$$

- 16.1 Capture coefficient & Capture Cross Section
- 16.2 Derivation of SRH formula (Shockley, Reed, Hall)
 - » 16.2.1 Trap Assisted Recombination Rates
 - » 16.2.2 Capture and emission relationship (n_1 and p_1)
 - » 16.2.3 Steady State Trap Population
 - » 16.2.4 Recombination-Generation Rate
- 16.3 Application of SRH formula for special cases
 - » Low level, high-level injection, depletion region
- 16.4 Direct and Auger recombination
- 16.5 Nature of interface states
- 16.6
- 16.7

